INTERMEDIATE PHASES IN THE SYSTEMS NIOBIUM-SELENIUM, NIOBIUM-TELLURIUM, TANTALUM-SELENIUM, AND TANTALUM-TELLURIUM

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(Received December 23rd, 1965)

SUMMARY

The phase relationships in the systems Nb–Se, Nb–Te, Ta–Se, and Ta–Te have been studied by X-ray diffraction and density measurements. The intermediate phases found in these systems are Nb₅Se₄, Nb₃Se₄, Nb_{1+x}Se₂ (0.00 $\leq x \leq$ 0.29; three polytype modifications 2H, 3R, and 4H), \sim NbSe₄ (three modifications α , β and γ), Nb₅Te₄, Nb₃Te₄, NbTe₂, NbTe₄, Ta_{1+x}Se₂ (0.00 $\leq x <$ 0.64; five modifications 1T, 2H, 3R, 4H ($4H_{(a)}$ or $4H_{(b)}$), and 6R), TaSe₃, TaTe₂, and TaTe₄. The intermediate phases found by us are compared with those reported by previous investigators of these systems. Most of the apparent inconsistencies are explained and resolved.

INTRODUCTION

The binary systems of niobium or tantalum in combination with one of the pnigogen or chalcogen elements have, in recent years, received considerable attention. The interest of workers in this field may be exemplified by the frequency of papers dealing with the systems Nb-Se, Nb-Te, Ta-Se, and Ta-Te. Whereas little information regarding these systems was available five years ago, twenty-eight out of thirty-three papers dealing with these systems (see Refs. 1-33) have appeared since that time, of which twenty-five have been published in the last two years*. The various groups of researchers have worked and published their results independently, and it is therefore not very surprising to find that some of their results are conflicting. On the other hand, it is disappointing to note that the utilization of results in the literature is so slow that obvious discrepancies remain without comment.

The present authors have previously reported on the structural properties of intermediate phases^{6,9,10,17,21,28–30,33} in the the systems Nb–Se, Nb–Te, Ta–Se, and Ta–Te. The purpose of this paper is to provide a comprehensive description of the results obtained in our phase-analytical surveys of these systems, and by comment and comparison with the information from the available literature, we hope to clarify which are intermediate phases and which are not. This discussion is prompted by the publication of two recent papers in this Journal^{12,13}.

The phase-analytical work with a given phase can, in outline, be divided into

^{*} See also "note added in proof" on page 30.

four activities, each of which requires a satisfactory answer before the phase analyst can regard the work as completed. These activities consist of:

- (1) Establishing the existence of the phase.
- (2) Determining possible thermal conditions for its existence.
- (3) Characterizing it for identification purposes by measurement of its chemical or physical properties.
 - (4) Stating its correct chemical composition.

A phase-analytical survey consists of providing unambiguous solutions to these four problems for all the phases of a system. In consideration of these factors, satisfactory surveys of the systems Nb-Se, Nb-Te, Ta-Se, and Ta-Te have not yet been reported. We find that the correct compositions of the intermediate phases in these systems have been frequently mis-stated. Bearing in mind that little value can be attached to the interpretation of measured chemical and physical properties on mixtures of two or more phases, the reliability of the characterization of some of the previously reported phases might be somewhat doubtful.

EXPERIMENTAL

The samples were prepared from 99.98% Nb, 99.92% Ta, 99.999+% Te (Johnson, Matthey & Co., Ltd.), and 99.998% Se (Bolidens Gruvaktiebolag). A series of samples was prepared by heating weighed quantities of metal and chalcogen in different ratios in evacuated and sealed silica tubes. The samples were heated to various temperatures between 400 and 1350°C, and quenching in ice water as well as slow cooling was applied.

X-ray diffraction (oscillation, Weissenberg, precession, and Guinier photographs) and density measurements were carried out as previously described^{6,9,10,21}. ^{28–30,33}

The existence of intermediate phases was established by the presence of their characteristic diffraction patterns in the X-ray powder (Guinier) photographs, and these patterns were used for a first, coarse characterization of the phases. The compositions of the intermediate phases were determined using the disappearing-phase principle on the X-ray powder photograph data and in some cases were also estimated from specific volume vs. composition (in wt. %) plots. For a more detailed description of these methods and their accuracy reference is made to Jensen et al.³⁴. Most of the intermediate phases considered in this paper have also been assigned a further characterization by the determination of their crystal structures (reported elsewhere^{6,9,10,21,29,30,33}) which provides accurate confirmation of the compositions stated. The derived compositions have furthermore been tested by comparison of the pycnometrically observed densities with those calculated on the basis of the structural data.

A particular difficulty encountered in investigating the metal-rich parts of the Nb–Se, Nb–Te, Ta–Se, and Ta–Te systems is due to the presence of apparently unavoidable interfering reactions between Nb and SiO₂, and Ta and SiO₂, respectively. These reactions are easily demonstrated by comparatively short heat treatments (five days at 1000°C) of the pure metals in evacuated and sealed silica tubes. The silica tubes are found to be heavily attacked after these heat treatments and their contents give X-ray powder photographs which are quite different from those of the pure metals. The products of the reaction between Nb and SiO₂ can, from the X-ray powder

photograph data, be identified as NbO and Nb₅Si₃ in accordance with the previous findings of Schäfer and Dohmann³⁵. Although the products of the reaction between Ta and SiO₂ are unidentified, they are thought to be analogous, *i.e.* tantalum oxide(s) and tantalum silicide(s).

The effects of the interfering reactions can be reduced (but not eliminated) by placing the samples in alumina crucibles inside the silica tubes. The reactions accordingly also take place *via* the gaseous phase. The latter observation is consistent with the findings of Schäfer and Dohmann³⁵ for the reaction between Nb and SiO₂. Contamination due to these reactions has been noticed in samples containing less than ~65 at.% Se, ~58 at.% Te, ~66.7 at.% Se, and ~66.7 at.% Te in the Nb-Se, Nb-Te, Ta-Se, and Ta-Te systems, respectively. The contamination is quite variable, even for samples with the same initial composition. The results obtained on highly contaminated samples are not included in this paper.

NAMING OF THE INTERMEDIATE PHASES

The previous authors have used somewhat different notations for naming the intermediate phases in the Nb-Se, Nb-Te, Ta-Se, and Ta-Te systems. Without a careful inspection of the notations adopted in the various papers, the reader might be considerably confused. Thus we find it appropriate to present a brief description of the nomenclature used in this paper:

(1) The chemical formula has only been used as the symbol to designate an intermediate phase if this designation is unambiguous, *i.e.* in the cases where only one phase exists at each composition.

Some of the previous authors, e.g. Novoselova et al. 18, use notations of the type γ -phase, NbTe_{2.33-4.00}, which has been simplified to γ -NbTe₃ by Revolinsky et al. 13. Double notations of this type are unnecessary and in the form used by Revolinsky et al. they might even be misleading due to the danger of confusing with the common use of Greek characters to distinguish different modifications of one and the same phase. (See (3) below.)

(2) In order to distinguish and designate the various polytypes of layer structures a prefix is added to the formula. The first part of this prefix is an integer which corresponds to half the number of X layers (X = metalloid) within the unit repeat distance along the c axis. (All the layer structures considered in this paper have an even number of X layers. Half the number of X layers is furthermore equal to the number of complete XMX triple-layers (M = metal) per unit length of the c axis.) The second part of the prefix is a letter which gives the symmetry of the unit cell, e.g. T, H, or R depending upon whether the symmetry is trigonal, hexagonal, or rhombohedral. To differentiate between different polytypes with equal numbers of X layers and equal crystal symmetry, a letter subscript in parentheses is included as a third part of the prefix. The symbol $4H_{(b)}$ -Ta_{1+x}Se₂ may be given as an example of the complete designation of an intermediate phase of this type.

This scheme of notation follows that introduced by Ramsdell³⁶ for naming polytypes of SiC (and later used by Mitchell³⁷ for naming polytypes of CdI_2), except for a factor of one half in the numerical part of the prefix.

The present notation agrees with that previously used by Brown and Beern-Tsen¹⁴ (see also Revolinsky *et al.*¹³) for naming the polytypes of NbSe₂ and TaSe₂.

If the second (and a possible third) part of the prefix is substituted by the letter s the notations used by Kadijk et al. (see also Jellinek³8,³9) for naming the NbSe2 and TaSe2 polytypes are obtained. The letter s is an abbreviation for slabs, and the total prefix ns indicates according to Kadijk et al. that the repeat unit in the c direction has a thickness of n XMX slabs (also called triple-layers or sandwiches). It must be mentioned that the letter s in the notations of Kadijk et al. (i), is almost superfluous as the information is given by the number n.

(3) Greek characters have been used to denote different modifications of intermediate phases for which the structural relationships are less marked (or unknown) and where the above rational nomenclature is difficult to apply.

PHASE ANALYTICAL RESULTS

A survey of the intermediate phases reported by the previous investigators $^{1-33}$ of the systems Nb–Se, Nb–Te, Ta–Se, and Ta–Te is given in Tables I–IV. The only intermediate phases found in the present phase-analytical study of these systems are Nb₅Se₄, Nb₃Se₄, Nb_{1+x}Se₂ (0.00 $\leq x \leq$ 0.29; three modifications $_2H$, $_3R$, and $_4H$), \sim NbSe₄ (three modifications $_3R$, and $_4H$), Nb₅Te₄, Nb₃Te₄, NbTe₂, NbTe₄, Ta_{1+x}Se₂ (0.00 $\leq x <$ 0.64; five modifications $_3R$, $_3R$, and $_3R$, TaSe₃, TaTe₂, and TaTe₄. The formulae of these phases constitute the first horizontal row in Tables I–IV. Application of the data stated in the literature for identification purposes makes it possible (in most cases with absolute certainty) to divide the intermediate phases described by the previous investigators into the same categories. Phases which are apparently identical, according to the available data, have been listed in the same column in Tables I–IV. The original designations of the phases used by the various authors have been retained in the construction of Tables I–IV. Abbreviated symbols indicating the kind of identification (characterizing properties) given by these authors have also been included.

Brief considerations and comments on the phase relationships in the four systems are presented below.

THE Nb-Se SYSTEM

In a coarse classification (Table I) of the Nb-Se system it is reasonable to consider essentially four intermediate phases, *i.e.* Nb₅Se₄, Nb₃Se₄, Nb_{1+x}Se₂, and NbSe₄.

The Nb₅Se₄ phase

Nb₅Se₄ has a tetragonal Ti₅Te₄ type structure⁶. The structure provides good characterization and determines the composition of this phase. No composition range of the Nb₅Se₄ phase is indicated. This phase has previously only been found by Selte and Kjekshus⁶, who state that it is difficult to obtain because of the reaction between Nb and SiO₂. The latter observation may explain why the Nb₅Se₄ phase has not been detected by the other investigators of the Nb–Se system.

The Nb₃Se₄ phase

The crystal structure of Nb₃Se₄ has been determined by Selte and Kjekshus⁹.

THE INTERMEDIATE PHASES OF THE ND-Se SYSTEM*

TABLE I

Authors	NbsSea	Nba Sea	$Nb_{1+*}Se_n$			NbSex	ALAKAH POLITON TOTAL BANK AND	And the second s
	•	,	$2H$ - $Nb_{1+x}Se_2$	$3R-Nb_{1+x}Se_2$	$4H$ - $Nb_{1+x}Se_2$	α-NbSe ₄	β-NbSe ₄	γ -NbSe ₄
Brixner³			x-NbSe ₂ u, sg, e NbSe u, sg		β-NbSe ₂ u, sg, d, e		- Additional	
Koerts ⁴			$^{ m NbSe}_{2}$					
Revolinsky et al.5			NbSe ₂ (NbSe _{1.90-2.35}) ¢					
Selte and Kjekshus ⁶	Nb ₅ Se ₄ u, s, d	$\mathrm{Nb_3Se_4}$						
Beerntsen et al.?			l.tNbSe ₂ e, u, s		h.t.-NbSe ₂ u, s			
Boes			$NbSe_2$ u, e, l					
Selte and Kjekshus ⁹	${ m Nb}_5{ m Se}_4$	Nb_3Se_4 u, s, d	$\mathrm{Nb}_{1+x}\mathrm{Se}_2$					
Selte and Kjekshus ¹⁰		${ m Nb_3Se_4}$	$N_{D_1+x}S_{Q_2}$ $(0.00 \le x \le 0.05,$ $0.17 \le x \le 0.29)$ u, s, d			'NbSe4"		
Kadiyk et al. ¹¹			$2s-\mathrm{NbSe}_{2s}$ u,s $2s-\mathrm{Nb}_{1+x}\mathrm{Se}_{2s}$	3s-NbSe ₂ u, s 3s-Nb _{1+x} Se ₂	4s-NbSe ₂ u, s $4s$ -NbI+ x Se ₂	NbSe ₃ ?		

	ea?		$_{ m e_{3}}$? $_{\eta} ext{-NbSc}_{ m s}$?	'.'*	e_4 β -NbS e_4 \sim NbS e_4 u, sg	c ₄ β-NbSc ₄ γ-NbSe ₄ X-ray
	η-NbSe ₃ ? <i>u</i> , <i>sg</i> , <i>t</i>		η -NbSe ₃ ?	"NbSe4" m	a -NbSe $_{4}$	α-NbSe ₄
	ζ -NbSe ₂ (Nb _{1.05} Se ₂ NbSe ₂) u, s, t	$_{u,\ s}^{4H-\mathrm{NbSe}_2}$	$\begin{array}{l} \zeta\text{-NbSe}_2\\ \text{(Nb}_{1.03}\text{Se}_2\text{-NbSe}_2)\\ \ell \end{array}$			$4H-Nb_{1+x}Se_2$ $(x = 0.05)$ u
	δ-Nb _{1.14} Se ₂ u, s, t	$3R$ -NbSe $_2$	δ-Nb _{1.14} Sc ₂			$3R-Nb_{1+x}Se_2$ $(x = 0.11)$
	γ-Nb _{1.3-1.2} Se ₂ ** ε-NbSe ₂ (Nb _{1.05} Se ₂ -NbSc ₂) u, s, t α-NbSe?	$_{2}H ext{-} ext{NbSc}_{2}$ $_{u}$, $_{s}$	$e\text{-NbSe}_2$ (Nb _{1.05} Se ₂ -NbSe ₂) e α -NbSe?	$Nb_{1+x}Se_2$ "		$2H-Nb_{1+x}Se_2$ $(0.00 \le x \le 0.29)$
$^{ m NbSe}_{1.1}$	$\frac{\beta}{\ell}$ -NbSe?			${ m Nb_3Se_4} \ m$		$\mathrm{Nb_3Sc_4}$
				${ m Nb_5Se_4}$		${ m Nb_5Se_4}$
Schäfer and Fuhr ¹²	REVOLINSKY et al. 13	Beentsen ¹⁴	REVOLINSKY et al. 15	Selte and Kjekshus ¹⁶	Selte and K_J ekshus ¹⁷	Present

* The phases reported by the previous investigators are included in the table with their original designations and the attached letters indicate the The following abbreviations have been used: u = unit cell dimensions, sg = space group, s = crystal structure, d = pyenometric density, m = magnetic susceptibility, e = electrical properties (electrical conductivity, thermoelectric power, Seebeck coefficient, superconduction transition temperature), l = lubricating properties, t = thermal stability.kind of characterization provided.

dentical phases are listed in the same column. When the identification is uncertain, either due to lack of data or inconsistencies, a question mark

is attached to the formula.

** Probably a mixture of several phases.

The formula Nb₃Se₄ is ascertained by the structure determination and by the comparison of the pycnometrically observed density with that calculated on the basis of the structural data. No indication of range of homogeneity is obtained.

The hexagonal NbSe_{1.1} phase reported by Schäfer and Fuhr¹² is obviously identical with the Nb₂Se₄ phase, although their analytically determined composition must accordingly be incorrect. (Comparison of unit-cell dimensions have been used to confirm the identity. Schäfer and Fuhr prepared single crystals of this phase by chemical-transport reactions using iodine as a transport agent. Single crystals of Nb₂Se₄ have been obtained by the same technique in the present study.)

The $Nb_{1+x}Se_2$ phase

The Nb_{1+x}Se₂ phase crystallizes in at least three polytype modifications. The crystal structures of these polytypes, named 2H-Nb_{1+x}Se₂, 3R-Nb_{1+x}Se₂, and 4H-Nb_{1+x}Se₂, have been determined by Selte and Kjekshus¹⁰, Kadijk *et al.*¹¹, and Brown and Beerntsen¹⁴. 2H-Nb_{1+x}Se₂, 3R-Nb_{1+x}Se₂, and 4H-Nb_{1+x}Se₂ have characteristic and closely-related layer structures.

The Nb_{1+x}Se₂ phase has a homogeneity range within the limits 60.8 and 66.67 at.% Se $(0.00 \le x \le 0.29)$ for slowly-cooled samples. The limits of the homogeneity range have been estimated from the dimensional variations in the unit cell(s) of 2H-Nb_{1+x}Se₂ (3R-Nb_{1+x}Se₂ and 4H-Nb_{1+x}Se₂) as a function of composition and by application of the disappearing-phase principle in the interpretation of the X-ray powder photograph data. As indicated by the formula Nb_{1+x}Se₂, density measurements have shown that the solid solution takes place by addition of Nb atoms as the composition of the phase varies from Nb_{1.00}Se₂ to Nb_{1.29}Se₂.

It has been difficult to obtain consistent, reproducible results within the homogeneity range due to the close structural relationship between 2H-Nb_{1+x}Se₂, 3R- $Nb_{1+x}Se_2$, and $4H-Nb_{1+x}Se_2$. A large number of the samples in this concentration range contained a mixture of two or three of the polytypes. The most consistent results are obtained after relatively short heat treatment. Re-annealing has generally not improved the samples, but has occasionally worsened the homogeneity. Usually, we have been able to prepare samples containing pure $2H-Nb_{1+x}Se_2$ for $0.00 \le x \le$ 0.05 and 0.17 $\le x \le$ 0.29. (Many samples with 0.17 $\le x \le$ 0.29 contained a mixture of two or three of the polytypes.) $3R-Nb_{1+x}Se_2$ and $4H-Nb_{1+x}Se_2$ have been obtained only in samples with bulk compositions corresponding to $x \ge 0.05$, most frequently in the range $0.05 \le x < 0.17$, and have almost invariably been obtained in admixture with one or two of the other polytypes. $3R-Nb_{1+x}Se_2$ has only been observed as a single phase at the composition ~ Nb_{1.11}Se₂. Approximately constant lattice dimensions* of 3R-Nb_{1+x}Se₂ are obtained, regardless of whether the samples consist of a mixture of polytypes or not. The unit cell dimensions** of 4H-Nb_{1+x}Se₂ are also found to be approximately constant in all our samples. The purest samples of 4H-

^{*} The values a = 3.459 Å, c = 18.79 Å have been found for 3R-Nb_{1.11}Se₂. These values agree reasonably well with those given by Kadijk *et al*.¹¹ (x>0?), Brown and Beerntsen¹⁴ (x>0), and Revolinsky *et al*.¹³ (x=0.14).

^{**} The values a = 3.449 Å, c = 25.19 Å have been obtained for 4H-Nb_{1+x}Se₂ in a sample with bulk composition corresponding to x = 0.05. These values are in reasonably good agreement with those stated by Kadijk *et al.*¹¹ (x = 0.00), Brown and Beerntsen¹⁴ (x = 0.00), and Revolinsky *et al.*¹³ (0.00 $\le x \le 0.05$).

 $Nb_{1+x}Se_2$ have been observed for a composition corresponding to x=0.05, which approaches an apparently single phase of $4H-Nb_{1+x}Se_2$. (The possible simultaneous presence of $2H-Nb_{1+x}Se_2$ and $4H-Nb_{1+x}Se_2$ is difficult to exclude on the basis of the present X-ray powder photograph data.)

The present results agree with those of Selte and Kjekshus¹⁰, Kadijk et al.¹¹, Revolinsky et al.^{13,15}, and Brown and Beerntsen¹⁴ regarding the structural characterization of the three polytypes of the Nb_{1+x}Se₂ phase. Bearing in mind the difficulties in obtaining reproducible results throughout the homogeneity range, the present results may be essentially consistent with those of the previous studies in respect of the occurrence of the various polytypes as a function of composition and temperature of preparation. A detailed consideration of the apparent discrepancies of Table I is in any case not justified at present. (See also the Ta_{1+x}Se₂ phase.)

The NbSe4 phase

The existence of three intermediate phases with compositions in the range 66.7–100 at.% Se has been established in the Nb–Se system. The exact compositions of these phases have not been determined, but two of them have been designated the composition NbSe₄ (named α -NbSe₄ and β -NbSe₄) on the basis of relationships in lattice dimensions and crystal symmetry with NbTe₄. The composition of the third phase is even less certain, but it is named γ -NbSe₄ for the lack of a better notation. α -NbSe₄ and β -NbSe₄ are characterized by the dimensions of their tetragonal unit cells¹⁷, and X-ray powder data for characterization of γ -NbSe₄ is given in Table V (see Appendix). Attempts are now being made to determine the crystal structure of β -NbSe₄ in order to establish its correct composition.

The rather limited data presented by Revolinsky *et al.*^{13,15} for their η -NbSe₃ phase (the composition has been corrected to NbSe₄ in the note added in proof), suggests that their phase may be identical with the α -NbSe₄ or β -NbSe₄ found by us.

THE Nb-Te SYSTEM

Four intermediate phases Nb₅Te₄, Nb₃Te₄, NbTe₂, and NbTe₄ have been observed in the Nb-Te system (cf. Table II).

The Nb₅Te₄ phase

 ${\rm Nb_5 Te_4}$ is isostructural with ${\rm Nb_5 Se_4}^6$. Comments already presented for the ${\rm Nb_5 Se_4}$ phase are indeed relevant also for the ${\rm Nb_5 Te_4}$ phase.

The X-ray powder photograph data, unit cell and observed density published by Novoselova *et al.*¹⁸ and Grigorjan *et al.*¹⁹ for their α-phase, NbTe_{0.18-0.82}, are inconsistent with the corresponding data for the Nb₅Te₄ phase. As an alternative interpretation, essentially consistent with the results, it may be suggested that their samples have been strongly contaminated with NbO and Nb₅Si₃. NbO and Nb₅Si₃ are the products of the reaction between Nb and SiO₂ and our suggestion appears accordingly to be quite plausible (see Experimental and also Refs. 6, 10, and 40).

The Nb₃Te₄ phase

Nb₃Te₄ is isostructural with Nb₃Se₄; it is well characterized and its stoichiometric composition is accurately determined⁹.

TABLE II
THE INTERMEDIATE PHASES OF THE Nb-Te system*

Authors	Nb_5Te_4	Nb_3Te_4	$NbTe_2$	$NbTe_4$
Novoselova et al.18		β -phase (NbTe _{1,00-1.70}) e		γ -phase (NbTe _{2.33-4.00}) e
Grigorjan et al. ¹⁹		eta-phase (NbTe _{1.00-1.70}) u		γ -phase (NbTe _{2.33-4.00}) u
Brixner ³			$NbTe_2$ u , sg , d , e $NbTe$ u , sg	
Chaigneau and Santarromana ²⁰			$ NbTe_2 $ u, d	
Selte and Kjekshus ⁶	Nb ₅ Te ₄ u, s, d	$\mathrm{Nb_{3}Te_{4}}$		
Boes8			NbTe2 u, e, l	
Selte and Kjekshus ⁹	$\mathrm{Nb_5Te_4}$	Nb_3Te_4 u, s, d	NbTe_{2} ?	
Selte and Kjekshus ²¹			$\mathrm{NbTe_{2}}?$	$ NbTe_4 $ u, s, d
Schäfer and Fuhr ¹²		$_{u}^{\mathrm{NbTe}_{1.0}}$	$\mathrm{NbTe_2}$	
REVOLINSKY et al. ¹³		α-NbTe?	$\begin{array}{l} \beta\text{-NbTe}_2\\ (\text{1}M\text{-NbTe}_2,\\ \text{Nb}_{1.06}\text{Te}_2\text{-NbTe}_2)\\ u,sg \end{array}$	γ-NbTe ₃ u, sg
Selte and Kjekshus ¹⁶	Nb ₅ Te ₄	Nb ₃ Te ₄ m	$^{\mathrm{NbTe_{2}}}$?	NbTe ₄
Brown ²²			$NbTe_2$ u, s, d	
Present	$\mathrm{Nb_5Te_4}$	$\mathrm{Nb_{3}Te_{4}}$	$ NbTe_2$? X-ray, d	$\mathrm{NbTe_{4}}$

^{*} See the footnote to Table I.

Identity between $\mathrm{Nb_3Te_4}$ and the phase $\mathrm{NbTe_{1.0}}$ reported by Schäfer and Fuhr¹² seems evident, despite the incorrect composition stated by the latter authors.

The β -phase, NbTe_{1.00-1.70}, described by Novoselova et al.¹⁸ and Grigorjan et al.¹⁹, is, according to the available data, probably also identical with Nb₃Te₄. The X-ray patterns published by Novoselova et al. suggest to us a narrow, rather than an extended range of homogeneity for their phase. The apparent disagreement in respect of the range of homogeneity of this phase may thus be overcome.

The NbTe2 phase

NbTe₂ is, according to the present study, characterized by the X-ray powder photograph data listed in Table VI (see APPENDIX). Inferred from the X-ray powder photographs, the disappearing-phase principle gave a composition close to the stoichiometric ratio 1:2. No significant shifts were obtained in the positions of the reflections on the X-ray powder photographs for samples with different initial proportions of the components, and the homogeneity range of this phase is accordingly rather narrow. Further support for the formula NbTe₂ was obtained from a specific volume vs. wt.% Te plot which showed a sharp break in the linearity at a composition corresponding to NbTe₂.

The present study concurs with the previous studies by BRIXNER³, BOES⁸, CHAIGNEAU AND SANTARROMANA²⁰, SCHÄFER AND FUHR¹², REVOLINSKY et al.¹³, and BROWN²² regarding the existence of a phase with composition NbTe₂. (REVOLINSKY et al. and BROWN propose a narrow range of homogeneity extending from NbTe₂ to Nb_{1.06}Te₂.) We have, however, been unable to match our diffraction data (Table VI) with their structural data, despite numerous attempts*. The most comprehensive of these structural data is due to BROWN²², who has derived a complete, and chemically very plausible, crystal structure from single-crystal X-ray data. BROWN claims furthermore that his NbTe₂ phase (and accordingly also that of REVOLINSKY et al.) is identical with the NbTe₂ phase of BRIXNER³ and Chaigneau and Santarromana²⁰. The structural data of BRIXNER have been confirmed by BOES⁸ and SCHÄFER AND FUHR¹². Further work is, however, needed to reveal the discrepancies between BROWN's and the present study.

Comparison of BRIXNER's structural data for his phases NbTe₂ and NbTe, suggests very strongly that the composition of the latter phase is incorrect and that the two phases in reality are identical, *i.e.* NbTe₂.

The NbTe₄ phase

The crystal structure of NbTe₄ has been determined by Selte and Kjekshus²¹. (Only the structure of the subcell is known, but since the additional reflections on oscillation and Weissenberg photographs were faint, the complete structure might be regarded as a slightly perturbed superstructure of that of the subcell.) The stoichiometric formula NbTe₄ is ascertained by the structure determination and by the comparison of the pycnometrically observed density with that calculated on the basis of the structural data.

The γ -phase, NbTe_{2.33-4.00}, reported by Novoselova et al.¹⁸ and Grigorjan et al.¹⁹ is, according to their X-ray data, no doubt identical with NbTe₄. The disagreement in respect of the range of homogeneity seems to reflect the weakness of the disappearing-phase principle in phase-analytical work by X-ray powder methods. (This statement applies also to the corresponding discussion of the Nb₃Te₄ phase above.) Our interpretation of the X-ray patterns published by Novoselova et al.¹⁸ suggests furthermore a narrow composition range for their phase.

The γ -NbTe₃ phase reported by Revolinsky *et al.*¹³ is also identical with NbTe₄. The disagreement in respect of composition is removed by the note added in

^{*} Some features of the data listed in Table VI are consistent with the unit cells of various sizes and symmetries proposed by the previous authors^{3,8,12,13,20,22}, but a far from perfect fit is attained with any.

proof, where Revolinsky et al. confirm that they accept the formula NbTe₄ found by Selte and Kiekshus²¹.

THE Ta-Se SYSTEM

According to the present study, the Ta-Se system (Table III) can be described roughly as having only two intermediate phases, *i.e.* $Ta_{1+x}Se_2$ and $TaSe_3$. Our results for the metal-rich part of the Ta-Se system are, however, less satisfactory than those obtained in the corresponding part of the Nb-Se system. Most of the samples in this concentration region have invariably been contaminated with impurities (in some cases in rather large amounts) resulting from the apparently unavoidable reaction between Ta and SiO₂. The present result concerning the suggested non-occurrence of intermediate phases with compositions between Ta and $Ta_{1+x}Se_2$ should thus be regarded as somewhat tentative.

The Ta1+xSe2 phase

Six polytype modifications of the $Ta_{1+x}Se_2$ phase have been reported, namely iT- $Ta_{1+x}Se_2$, 2H- $Ta_{1+x}Se_2$, 3R- $Ta_{1+x}Se_2$, $4H_{(a)}$ - $Ta_{1+x}Se_2$, $4H_{(b)}$ - $Ta_{1+x}Se_2$, and 6R- $Ta_{1+x}Se_2$. The six polytypes have characteristic and closely-related layer structures according to structure determinations by Kadijk *et al.*¹¹, Brown and Beerntsen¹⁴, and Bierkelund and Kiekshus³⁰.

The $Ta_{1+x}Se_2$ phase has a homogeneity range within the limits 55.0 and 66.67 at.% Se $(0.00 \le x < 0.64)$ for slowly-cooled samples. The extension of the composition range has been estimated from the changes in the dimensions of the unit cells of the various polytypes as a function of composition and using the disappearing-phase principle in the interpretation of the X-ray powder photograph data. The comparison of the pycnometrically observed densities with those calculated from the structural data confirms that the solid solution takes place according to the formula $Ta_{1+x}Se_2$.

Our previous statements concerning the difficulties in obtaining reproducible results within the homogeneity range of the Nb_{1+x}Se₂ phase are equally valid also for the Ta_{1+x}Se₂ phase. Although most of our samples within the composition range of the Ta_{1+x}Se₂ phase have turned out to contain a mixture of two or three of the polytypes, some general trends have been noticed for the occurrence of the different polytypes of Ta_{1+x}Se₂. iT-Ta_{1+x}Se₂ and iT-Ta_{1+x}Se₂ have been obtained only for iT-0.00, i-iT-0.01 at the stoichiometric composition TaSe₂. (It should be noted that we have been unable to distinguish between iT-Ta_{1+x}Se₂ and iT-Ta_{1+x}Se₂ on the basis of our present data.) Samples containing pure iT-Ta_{1+x}Se₂ have been obtained for iT-0.03 and iT-0.25 and iT-Ta_{1+x}Se₂ and iT-Ta_{1+x}Se₂ have been noted for iT-0.03 and iT-Ta_{1+x}Se₂ however, invariably in mixture with one or two of the other polytypes. (For details regarding the structural data, reference is made to Bjerkelund and Kjekshus³⁰.)

Except for the uncertainty regarding $4H_{(a)}$ -Ta_{1+x}Se₂ and $4H_{(b)}$ -Ta_{1+x}Se₂, our structural characterization of the various polytypes of the Ta_{1+x}Se₂ phase appears to be in agreement with that of Kadijk *et al.*¹¹, Brown and Beerntsen¹⁴, and Revolinsky *et al.*¹³. As was the case for the Nb_{1+x}Se₂ phase, a detailed consideration of the apparent discrepancies of Table III with regard to the occurrence of the polytypes as a function of composition is not considered to be justified.

The intermediate phases of the Ta-Sc system*

Authors	$Ta_{1+x}Se_2$		Woodship Printer the Colonia was a colonia with the colonia was a coloni	* I I I I I I I I I I I I I I I I I I I		ON THE PROPERTY OF THE PROPERT	TaSes
	LT - $Ta_{1+x}Se_{2}$	2H-Ta _{1+x} Se ₂	$3R-Ta_{1+x}Se_{2}$	4H(a)-Ta1+xSe2	4H(b)-Ta1+xSe2	$6R$ - $Ta_{1-x}Se_2$	
Ariya et al. ²³		lpha-phase?					higher selenide?
$Brixner^3$		x-TaSe ₂ u, sg, d, e TaSe	β -TaSe ₂ u, sg, e				
Brixner ²⁴		u, 5g	TaSc2				
ASLANOV et al. 26	α -TaSe ₂ u	β -TaSc _{1.98} u, d, e	n, 58, <i>e</i>			δ -TaSe _{1.98} u	$\operatorname*{TaSe}_{\theta}$
ASLANOV et al. 27							$_{u}^{\mathrm{TaSe_{3}}}$
Boes		TaSe ₂ u, e, l					
Bjerkelund and Kjekshus ²⁸							TaSe ₃ u, d, m
Kadijk et al. 11		2s-TaSe ₂ u, s	3s-TaSe ₂ u, s	4s-TaSe ₂		6s-TaSe ₂ u, s	$TaSe_3$?
Brown and Beerntsen ¹⁴		$_{2}H$ -TaSe ₂			$_{u, s}^{+H-TaSc_2}$		
Revolinsky $\it et al.18$		e-TaSc ₂ (2H-TaSe ₂) u, s α-TaSe? β-TaSe?		⊊-TaSe₂?	4 <i>H</i> -TaSe ₂ <i>u</i> , <i>s</i>	0-Ta _{1.65-1.05} Se ₂ ?	η -TaScs?
Bjerkelund and Kjekshus ²⁹							TaSes u, s, d
Bjerkelund and Kjekshus³0	$ \begin{array}{l} 1 T - T \mathbf{a}_{1 + x} Se_2 \\ (x = 0.00) \\ u, s, t \end{array} $	$2H-Ta_{1+x}Sc_{2}$ (0.00 \leq x < 0.03; 0.25 < x < 0.64) 0.5	3R-Ta _{1+x} Se ₂ ? (0.03 < x < 0.25)	$_{u}^{4H-Ta_{1+x}Se_{2}}$	$4H-Ta_{1+x}Sc_2?$ $(x = 0.00)$ u	$6R\text{-Ta}_{1+x}\text{Se}_2$? (0.03 < x < 0.25)	
Present	$_{(x = 0.00)}^{1T\text{-}Ta_{1+x}}Se_{2}$	$2H \cdot Ta_{1-x} Se_2$ (0.00 $\leq x < 0.03$; 0.25 $< x < 0.64$)	$\frac{3R\text{-Ta}_{1+x}Se_2?}{(0.03 < x < 0.25)}$	$_{1}^{+H-Ta_{1+x}}Se_{2}$	$4H \cdot Ta_{1-x} Se_2 $ ($\kappa = 0.00$)	$\frac{6R\text{-Ta}_{1+x}Se_2?}{(0.03 < x < 0.25)}$	TaSe ₃
THE RESIDENCE OF THE PARTY OF T	The second of the second secon	C (TOTAL DESCRIPTION OF THE PARTY OF T			THE RESIDENCE AND ADDRESS OF THE PARTY ADDRESS OF THE PARTY AND ADDRESS OF THE PARTY AN		Control of the last of the las

* See the footnote to Table I.

The available information on the $\mathrm{Nb_{1+x}Se_2}$ and $\mathrm{Ta_{1+x}Se_2}$ phases suggests, as previously pointed out by Kadijk et al. 11 (see also Jellinek 38,39), that the relationships between the different polytypes are governed not only by thermodynamics, but that the kinetics of crystal growth are of importance. The current theory for the formation of polytype phases (cf. Mitchell 37 where further references also are given) assumes that polytypism results from the spiral growth of crystals, initiated by screw dislocations. The exposed steps from which the various polytypes grow must be of different heights and contain at least one departure from the "ideal" (basic) structure of the phase. This theory of polytypism would, according to Mitchell 37, be proved reasonably well if the crystals of a given polytypic substance show each of the following features:

- (1) Growth spirals.
- (2) Spiral step heights of various magnitudes.
- (3) Structures which could be interpreted as having resulted from dislocations of various magnitudes in an "ideal" (basic) crystal structure.

To test the theory Mitchell³⁷ has used CdI_2 , for which he reports the existence of at least 32 different polytypes. The three characteristic features have been satisfactorily confirmed by the experimental data for CdI_2 , indicating that the theory is essentially correct.

The polytypes of the $\mathrm{Nb_{1+x}Se_2}$ and $\mathrm{Ta_{1+x}Se_2}$ phases are closely-related structurally to those of $\mathrm{CdI_2}$. $\mathrm{Ta_{1+x}Se_2}$ and $\mathrm{CdI_2}$ have even one polytype in common, *i.e.* that corresponding to $\mathrm{I}T\text{-}\mathrm{Ta_{1+x}Se_2}$ with x=0.00 (normally denoted the $\mathrm{Cd}(\mathrm{OH})_{2}$ -type). It seems natural therefore to attempt an explanation of the observed polytypism of the $\mathrm{Nb_{1+x}Se_2}$ and $\mathrm{Ta_{1+x}Se_2}$ phases in terms of the same theory.

- (I) Growth spirals on the (001) faces of the hexagonal plate-shaped crystals of the $Nb_{1+x}Se_2$ and $Ta_{1+x}Se_2$ phases have been observed by microscopic examination.
- (2) Indication of spiral step heights of various magnitudes has been obtained, but no quantitative measurements have been carried out to confirm this point.
- (3) The screw dislocation theory of crystal growth supplies a satisfactory mechanism for generating the structures of the known polytypes of the Nb_{1+x}Se₂ and Ta_{1+x}Se₂ phases. The basic crystal structure of these phases is considered to be that of 2H-Nb_{1+x}Se₂ (2H-Ta_{1+x}Se₂), which is consistent with the observation that this polytype is noticed far more frequently than the others. The structures of the polytypes 3R-Nb_{1+x}Se₂ (3R-Ta_{1+x}Se₂), $4H_{(a)}$ -Ta_{1+x}Se₂ (4H-Nb_{1+x}Se₂), and $4H_{(b)}$ -Ta_{1+x}Se₂ can be generated from one or two co-operating screw dislocations acting along [001] with Burgers vector(s) equal to half the c axis of 2H-Nb_{1+x}Se₂ and 2H-Ta_{1+x}Se₂ respectively. The structure of the polytype iT-Ta_{1+x}Se₂ can be accounted for by assuming an alternate arrangement of the initial Ta and Se atoms as they take their places at the bottom of a growing step. In order to explain the occurrence of the polytype 6R-Ta_{1+x}Se₂ the effects of both screw dislocations and alternate arrangement of the Ta and Se atoms at the bottom of the growing step must be considered. (For a more detailed discussion reference is made to MITCHELL³⁷ and Jellinek³⁸.)

It is well known that chemical impurities and interstitial atoms can produce dislocations and, accordingly, also give rise to polytypes. Chemical impurities (resulting from the reactions between Nb and SiO_2 and Ta and SiO_2 respectively) and interstitial atoms (as indicated by the formulae $Nb_{1+x}Se_2$ and $Ta_{1+x}Se_2$) are indeed present in these phases. The observed polytypism of the $Nb_{1+x}Se_2$ and $Ta_{1+x}Se_2$ phases

is therefore consistent with expectation. It may finally be predicted that further polytypes of these phases will occur.

The TaSe₃ phase

The crystal structure of TaSe₃ has been solved by Bjerkelund and Kjekshus²⁹. The comparison of observed and calculated densities^{28,29} and the characteristic crystal structure determine the stoichiometric formula TaSe₃.

The X-ray data for the TaSe₃ phase of Aslanov *et al.*^{26,27} gives unambiguous confirmation of identity with the present TaSe₃ phase.

The situation with respect to the η -TaSe₃ phase reported by Revolinsky et $al.^{13}$ is rather unclear. Revolinsky et al. state that η -TaSe₃ is isostructural with η -NbSe₃. (Compare the comments regarding the NbSe₄ phase. It must furthermore be emphasized that we have invariably obtained the same TaSe₃ phase in our samples despite numerous attempts in which different preparation temperatures and varying initial compositions of the samples have been used.) Revolinsky et $al.^{13}$ have apparently changed their minds with respect to the composition of their phase and state in the note added in proof that their corrected formula should be η -TaSe₄.

THE Ta-Te SYSTEM

The existence of two intermediate phases, *i.e.* TaTe₂ and TaTe₄, has been established by our study of the Ta–Te system (*cf.* Table IV). In view of the contamination of our Ta-rich samples, resulting from reaction between Ta and SiO₂, considerations concerning the possible existence of the two modifications of the TaTe_{0.85-1.2} phase reported by UKRAINSKII *et al.*^{31,32} and the β -TaTe phase reported by Revolinsky *et al.*¹³ seem hardly to be justified.

The TaTe2 phase

Characterization and determination of composition for the TaTe₂ phase has been carried out as previously described for NbTe₂ (cf. Table VI).

Brown²² has shown that TaTe₂ is isostructural with NbTe₂, and states that his TaTe₂ phase (and accordingly that of Revolinsky *et al.*¹³) is identical with the TaTe₂ phase of Brixner³ and the TaTe_{1.5-2.0} phase of Ukrainskii *et al.*^{31,32}. (The TaTe₂ phase of Boes⁸ is obviously identical with that of Brixner.)

Revolinsky et al. ¹³ and Brown ²² state that their TaTe₂ phase exhibits a range of homogeneity extending from TaTe₂ to TaTe (for samples prepared below 800°C), but they have not published any data supporting this statement, cf. Brixner³. Although this investigation has been concluded without giving a satisfactory answer to whether the present TaTe₂ phase is identical with that of Brown ²² it has definitely shown that our TaTe₂ phase has a rather narrow range of homogeneity.

The TaTe₄ phase

TaTe₄ is isostructural with NbTe₄; the crystal structure of the subcell has been determined by Bjerkelund and Kjekshus³³. (Regarding characterization and composition, see our comments on the NbTe₄ phase.)

The TaTe₃ phase found by UKRAINSKII *et al.*³¹ and the γ -TaTe₃ phase (the composition has been corrected to TaTe₄ in the note added in proof) found by Revo-

TABLE IV
THE INTERMEDIATE PHASES OF THE Ta-Te system*

Authors	$TaTe_2$	$TaTe_4$
UKRAINSKII et al. ³¹	β -phase (TaTe _{1.5-2.0})	ТаТе ₃ и, е
UKRAINSKII et al. ³²	eta-phase (TaTe _{1.5-2.0}) u , e	
Brixner ³	$TaTe_2$ u , sg , d , e $TaTe$ u , sg	
Boes ⁸	TaTe ₂ u, e, l	
Bjerkelund and Kjekshus ²⁸		$TaTe_4$ u, d, m
Bjerkelund and Kjekshus ³³		$TaTe_4$ u, s, d
Revolinsky et al. ¹³	IM-TaTe ₂ u, sg , $t(\alpha-Ta2.0-1.0Te2, < 800^{\circ}C)(\beta-Ta1.16-1.0Te2, > 800^{\circ}C)$	γ-TaTes u, sg
$ m Brown^{22}$	$TaTe_2$ u , s , d	
Present	$TaTe_2$? X-ray, d	${ m TaTe_4}$

^{*} See the footnote to Table I.

LINSKY et al.¹³ are undoubtedly identical with the present TaTe₄ phase. (The unit cell dimensions have been used to confirm identity.) The composition stated by the former authors is, however, somewhat erroneous.

THE Nb-S AND Ta-S SYSTEMS

Although the Nb-S and Ta-S systems have not been included in the present study, it has been considered to be of some interest to quote the intermediate phases of these systems for a brief comparison with those of the Nb-Se, Nb-Te, Ta-Se, and Ta-Te systems. The existence of the following intermediate phases is reported in the Nb-S and Ta-S systems: NbS_{1-x} ($x \approx 0.1$ -?, at >850°C), l.t.-NbS_{1-x} ($x \approx 0.0$ -0.15, at <800°C), 2H-Nb_{1+x}S₂ ($x \approx 0.30$ -0.43, at >1100°C), 3R-Nb_{1+x}S₂ ($x \approx 0.12$ -0.5, at 800°C; $x \approx 0.12$ -0.25, at 1100°C), 2H-NbS₂ (at >850°C), 3R-NbS₂ (at <800°C), NbS₃, 2H-Ta_{1+x}S₂ ($x \approx 0.2$ -0.35), 6R-Ta_{1+x}S₂ ($x \approx 0.2$), 3R-Ta_{1+x}S₂ ($x \approx 0.15$), random-TaS₂, 6R-TaS₂, 3R-TaS₂, 2H-TaS₂, 1T-TaS₂, and TaS₃. (The results of Jellinek et al.⁴¹, Jellinek ^{38,39} and Bjerkelund and Kjekshus²⁸ have been quoted.)

Two similarities are seen on comparing the intermediate phases of the M-X systems (M = Nb or Ta, X = S, Se, or Te):

- (1) The existence of a polychalcogenide phase has been established in all the M-X systems (NbS₃, \sim NbSe₄, NbTe₄, TaS₃, TaSe₃, and TaTe₄).
- (2) The sulfur and selenium systems of niobium and tantalum have, in common, phases with a general formula $M_{1+x}X_2$. Ranges of homogeneity have been observed for these phases, which furthermore, form several structurally closely-related polytypes.

APPENDIX

TABLE V

X-ray powder photograph data (Cu $K\alpha_1$ -radiation) for characterization of γ -NbSe₄

$sin^2 heta imes$ 10	5 and I_{obs} .		
871 m	4600 vw	6134 m	9015 W
877 m	4624 vw	6549 w	9093 st
1476 vst	4685 vw	6751 w	9186 w
1636 st	4792 VW	7074 VW	9292 W
1688 st	4906 m	7320 vw	9414 m
1865 vw	4939 m	7455 W	9518 m
1886 vw	4984 vw	7535 m	9621 m
2342 W	5143 VW	7711 m	10407 m
2414 W	5460 w	7814 W	10659 m
3577 m	5529 W	7917 m	10987 w
4241 VW	5918 w	8100 W	11283 W

TABLE VI X-ray powder photograph data (Cu $K\alpha_1$ -radiation) for characterization of NbTe2 and TaTe2

$sin^2 \theta \times I$	05 and lobs	$sin^2 heta imes 1e$	5 and I obs	$sin^2 \theta imes 16$	5 and I_{obs}
$NbTe_{2}$	$TaTe_2$	$NbTe_2$	$TaTe_3$	$NbTe_2$	$TaTe_2$
769 vw	781 w		8629 vw	15827 vw	15836 vw
	1246 vw	9077 W	9113 m		16211 vw
1344 m	1315 st		9862 vw	17296 st	17448 st
	2724 VW	10226 vw	10094 vw	17924 m	17684 m
	3130 VW	10298 vw	10359 m	18173 vw	
3912 vw	3932 vw	10740 vw	10740 W	18415 vw	18497 w
4412 VW		10929 VW	10891 w	18844 vw	18653 vw
4482 vw		11239 m	111 23 st	19255 VW	19255 W
	5226 vw		11195 W		19635 vw
5396 w	5286 vw	11369 w	11289 m		19916 vw
	5929 VW	12133 vw	11872 w		20477 VW
6168 vw	6147 vw		12265 vw	21608 vw	21121 W
6958 st	7005 st	12408 vw	12451 W	22405 vw	22341 VW
7115 vw			12506 w	22713 vw	22505 vw
7184 vw		12779 VW	12860 w	22937 vw	22962 W
7282 vst	7277 vst	14063 vw	14088 w	23312 vw	
7908 vw	7767 vw		14805 vw	23749 VW	24218 W
8282 vw			15264 vw	24323 VW	24522 m
8347 vw		15642 VW	15516 vw	24909 W	24943 m

Reflections which appear to be corresponding reflections for ${\rm NbTe_2}$ and ${\rm TaTe_2}$ are printed in italics.

Pycnometric densities at 25.00°C: NbTe₂ 7.33 g cm⁻³; TaTe₃ 9.16 g cm⁻³.

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Note added in proof, April 12th, 1966

Since this article was accepted for publication two further articles^{42,43} have appeared which deal with the properties of $_2H$ -Nb_{1+x}Se₂ and $_2H$ -Ta_{1+x}Se₂, respectively. The conclusions of the present are, however, unaffected.